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Details

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Product Status	Active
Core Processor	H8/300H
Core Size	16-Bit
Speed	20MHz
Connectivity	SCI
Peripherals	PWM, WDT
Number of I/O	30
Program Memory Size	32KB (32K x 8)
Program Memory Type	FLASH
EEPROM Size	-
RAM Size	2K x 8
Voltage - Supply (Vcc/Vdd)	3V ~ 5.5V
Data Converters	A/D 4x10b
Oscillator Type	Internal
Operating Temperature	-20°C ~ 75°C (TA)
Mounting Type	Surface Mount
Package / Case	48-LQFP
Supplier Device Package	48-LQFP (10x10)
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Symbol		Description
:3/:8/:16/:24		3-, 8-, 16-, or 24-bit length
Note: *	Gene	ral registers include 8-bit registers (R0H to R7H, R0L to R7L), 16-bit registers (R0

to R7, E0 to E7), and 32-bit registers/address registers (ER0 to ER7).

Table 2.2 Data Transfer Instructions

Instruction	Size*	Function				
MOV	B/W/L	$(EAs) \rightarrow Rd, Rs \rightarrow (EAd)$ Moves data between two general registers or between a general register and memory, or moves immediate data to a general register.				
MOVFPE	В	$(EAs) \rightarrow Rd$, Cannot be used in this LSI.				
MOVTPE	В	$Rs \rightarrow$ (EAs) Cannot be used in this LSI.				
POP	W/L	@SP+ \rightarrow Rn Pops a general register from the stack. POP.W Rn is identical to MOV.W @SP+, Rn. POP.L ERn is identical to MOV.L @SP+, ERn.				
PUSH	W/L	$Rn \rightarrow @-SP$ Pushes a general register onto the stack. PUSH.W Rn is identical to MOV.W Rn, @-SP. PUSH.L ERn is identical to MOV.L ERn, @-SP.				
Note: * Re	efers to the	operand size.				
B: Byt	е					
W: W	ord					
L: Lor	gword					



7.5 Program/Erase Protection

There are three kinds of flash memory program/erase protection; hardware protection, software protection, and error protection.

7.5.1 Hardware Protection

Hardware protection refers to a state in which programming/erasing of flash memory is forcibly disabled or aborted because of a transition to reset, subsleep mode or standby mode. Flash memory control register 1 (FLMCR1), flash memory control register 2 (FLMCR2), and erase block register 1 (EBR1) are initialized. In a reset via the $\overline{\text{RES}}$ pin, the reset state is not entered unless the $\overline{\text{RES}}$ pin is held low until oscillation stabilizes after powering on. In the case of a reset during operation, hold the $\overline{\text{RES}}$ pin low for the $\overline{\text{RES}}$ pulse width specified in the AC Characteristics section.

7.5.2 Software Protection

Software protection can be implemented against programming/erasing of all flash memory blocks by clearing the SWE bit in FLMCR1. When software protection is in effect, setting the P or E bit in FLMCR1 does not cause a transition to program mode or erase mode. By setting the erase block register 1 (EBR1), erase protection can be set for individual blocks. When EBR1 is set to H'00, erase protection is set for all blocks.

7.5.3 Error Protection

In error protection, an error is detected when CPU runaway occurs during flash memory programming/erasing, or operation is not performed in accordance with the program/erase algorithm, and the program/erase operation is aborted. Aborting the program/erase operation prevents damage to the flash memory due to overprogramming or overerasing.

When the following errors are detected during programming/erasing of flash memory, the FLER bit in FLMCR2 is set to 1, and the error protection state is entered.

- When the flash memory of the relevant address area is read during programming/erasing (including vector read and instruction fetch)
- Immediately after exception handling excluding a reset during programming/erasing
- When a SLEEP instruction is executed during programming/erasing



9.5 Port 8

Port 8 is a general I/O port also functioning as a timer W I/O pin. Each pin of the port 8 is shown in figure 9.5. The register setting of the timer W has priority for functions of the pins P84/FTIOD, P83/FTIOC, P82/FTIOB, and P81/FTIOA. The P80/FTCI pin also functions as a timer W input port that is connected to the timer W regardless of the register setting of port 8.

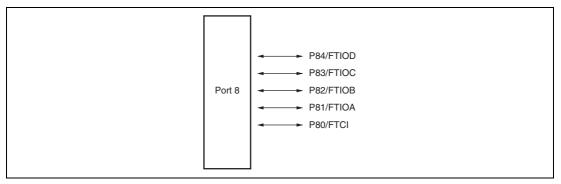


Figure 9.5 Port 8 Pin Configuration

Port 8 has the following registers.

- Port control register 8 (PCR8)
- Port data register 8 (PDR8)

9.5.1 Port Control Register 8 (PCR8)

PCR8 selects inputs/outputs in bit units for pins to be used as general I/O ports of port 8.

D '/		Initial	5.44	
Bit	Bit Name	Value	R/W	Description
7 to 5				Reserved
4	PCR84	0	W	When each of the port 8 pins P84 to P80 functions as an
3	PCR83	0	W	general I/O port, setting a PCR8 bit to 1 makes the corresponding pin an output port, while clearing the bit to
2	PCR82	0	W	0 makes the pin an input port.
1	PCR81	0	W	
0	PCR80	0	W	

11.2 Input/Output Pins

Table 11.2 summarizes the timer W pins.

Table 11.2 Pin Configuration

Name	Abbreviation	Input/Output	Function
External clock input	FTCI	Input	External clock input pin
Input capture/output compare A	FTIOA	Input/output	Output pin for GRA output compare or input pin for GRA input capture
Input capture/output compare B	FTIOB	Input/output	Output pin for GRB output compare, input pin for GRB input capture, or PWM output pin in PWM mode
Input capture/output compare C	FTIOC	Input/output	Output pin for GRC output compare, input pin for GRC input capture, or PWM output pin in PWM mode
Input capture/output compare D	FTIOD	Input/output	Output pin for GRD output compare, input pin for GRD input capture, or PWM output pin in PWM mode

11.3 Register Descriptions

The timer W has the following registers.

- Timer mode register W (TMRW)
- Timer control register W (TCRW)
- Timer interrupt enable register W (TIERW)
- Timer status register W (TSRW)
- Timer I/O control register 0 (TIOR0)
- Timer I/O control register 1 (TIOR1)
- Timer counter (TCNT)
- General register A (GRA)
- General register B (GRB)
- General register C (GRC)
- General register D (GRD)

11.4 Operation

The timer W has the following operating modes.

- Normal Operation
- PWM Operation

11.4.1 Normal Operation

TCNT performs free-running or periodic counting operations. After a reset, TCNT is set as a freerunning counter. When the CTS bit in TMRW is set to 1, TCNT starts incrementing the count. When the count overflows from H'FFFF to H'0000, the OVF flag in TSRW is set to 1. If the OVIE in TIERW is set to 1, an interrupt request is generated. Figure 11.2 shows free-running counting.

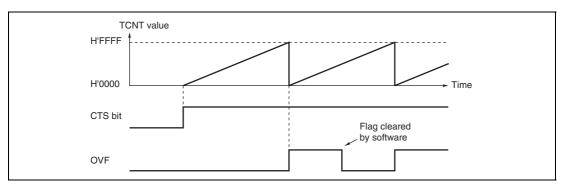


Figure 11.2 Free-Running Counter Operation



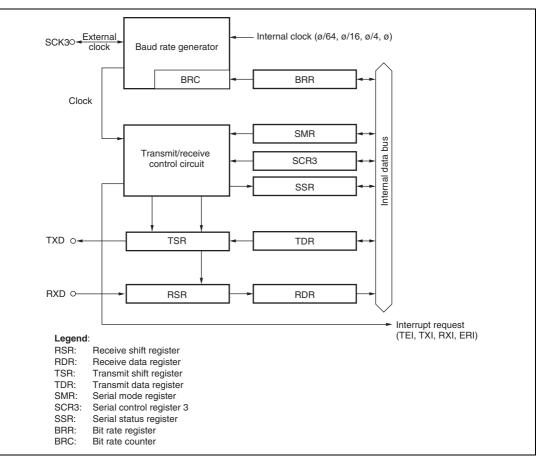


Figure 13.1 Block Diagram of SCI3

Table 13.5 Examples of BRR Settings for Various Bit Rates (Clocked Synchronous Mode) (2)

	Operating Frequency					
Bit Rate	18		2	20		
(bit/s)	n	Ν	n	Ν		
110	_	_	_	_		
250	_	_	_	_		
500	3	140	3	155		
1k	3	69	3	77		
2.5k	2	112	2	124		
5k	1	224	1	249		
10k	1	112	1	124		
25k	0	179	0	199		
50k	0	89	0	99		
100k	0	44	0	49		
250k	0	17	0	19		
500k	0	8	0	9		
1M	0	4	0	4		
2M	_		_	_		
2.5M	_	_	0	1		
4M	—	—	_	—		

Legend

Blank : No setting is available.

- : A setting is available but error occurs. ____
- : Continuous transfer is not possible. *

13.4 Operation in Asynchronous Mode

Figure 13.2 shows the general format for asynchronous serial communication. One character (or frame) consists of a start bit (low level), followed by data (in LSB-first order), a parity bit (high or low level), and finally stop bits (high level). Inside the SCI3, the transmitter and receiver are independent units, enabling full-duplex. Both the transmitter and the receiver also have a double-buffered structure, so data can be read or written during transmission or reception, enabling continuous data transfer.

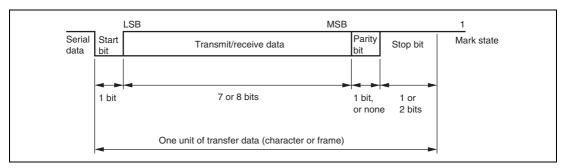


Figure 13.2 Data Format in Asynchronous Communication

13.4.1 Clock

Either an internal clock generated by the on-chip baud rate generator or an external clock input at the SCK3 pin can be selected as the SCI3's serial clock, according to the setting of the COM bit in SMR and the CKE0 and CKE1 bits in SCR3. When an external clock is input at the SCK3 pin, the clock frequency should be 16 times the bit rate used.

When the SCI3 is operated on an internal clock, the clock can be output from the SCK3 pin. The frequency of the clock output in this case is equal to the bit rate, and the phase is such that the rising edge of the clock is in the middle of the transmit data, as shown in figure 13.3.

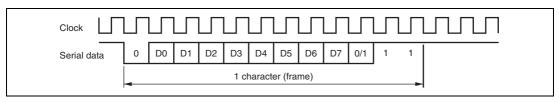


Figure 13.3 Relationship between Output Clock and Transfer Data Phase (Asynchronous Mode)(Example with 8-Bit Data, Parity, Two Stop Bits)

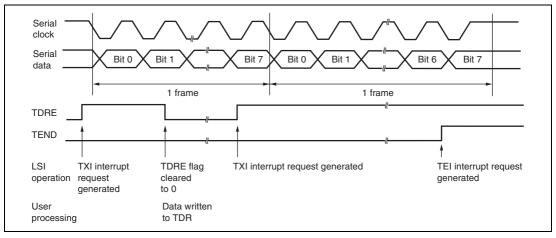


Figure 13.10 Example of SCI3 Transmission in Clocked Synchronous Mode

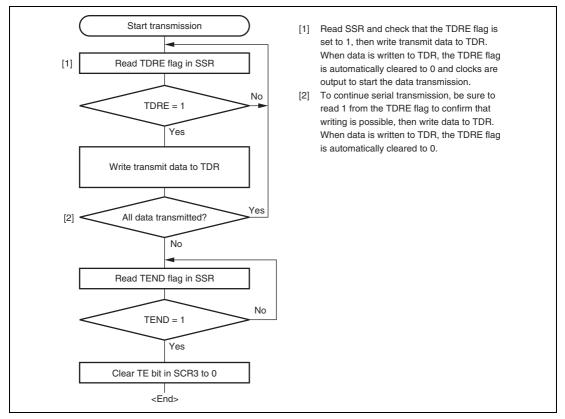
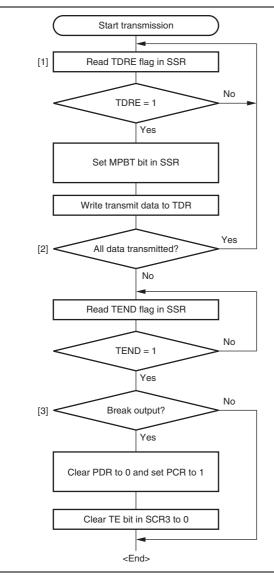


Figure 13.11 Sample Serial Transmission Flowchart (Clocked Synchronous Mode)





- Read SSR and check that the TDRE flag is set to 1, set the MPBT bit in SSR to 0 or 1, then write transmit data to TDR. When data is written to TDR, the TDRE flag is automatically cleared to 0.
- [2] To continue serial transmission, be sure to read 1 from the TDRE flag to confirm that writing is possible, then write data to TDR. When data is written to TDR, the TDRE flag is automatically cleared to 0.
- [3] To output a break in serial transmission, set the port PCR to 1, clear PDR to 0, then clear the TE bit in SCR3 to 0.

Figure 13.16 Sample Multiprocessor Serial Transmission Flowchart



Section 14 A/D Converter

This LSI includes a successive approximation type 10-bit A/D converter that allows up to four analog input channels to be selected. The block diagram of the A/D converter is shown in figure 14.1.

14.1 Features

- 10-bit resolution
- Four input channels
- Conversion time: at least 3.5 µs per channel (at 20 MHz operation)
- Two operating modes
 - Single mode: Single-channel A/D conversion
 - Scan mode: Continuous A/D conversion on 1 to 4 channels
- Four data registers
 - Conversion results are held in a 16-bit data register for each channel
- Sample and hold function
- Two conversion start methods
 - Software
 - External trigger signal
- Interrupt request
 - An A/D conversion end interrupt request (ADI) can be generated



	L١	/DCR Se	ttings		Select Functions			
LVDE	LVDSEL	LVDRE	LVDDE	LVDUE	Power-On Reset	LVDR	Low-Voltage- Detection Falling Interrupt	Low-Voltage- Detection Rising Interrupt
0	*	*	*	*	0	_	_	_
1	1	1	0	0	0	0	_	_
1	0	0	1	0	0	_	0	_
1	0	0	1	1	0	—	0	0
1	0	1	1	1	0	0	0	0

Table 15.1 LVDCR Settings and Select Functions

Legend * means invalid.

15.2.2 Low-Voltage-Detection Status Register (LVDSR)

LVDSR indicates whether the power-supply voltage falls below or rises above the respective specified values.

Bit	Bit Name	Initial Value	R/W	Description
7 to 2		All 1	_	Reserved
				These bits are always read as 1, and cannot be modified.
1	LVDDF	0*	R/W	LVD Power-Supply Voltage Fall Flag
				[Setting condition]
				When the power-supply voltage falls below Vint (D) (typ. = 3.7 V)
				[Clearing condition]
				Writing 0 to this bit after reading it as 1
0	LVDUF	0*	R/W	LVD Power-Supply Voltage Rise Flag
				[Setting condition]
				When the power supply voltage falls below Vint (D) while the LVDUE bit in LVDCR is set to 1, then rises above Vint (U) (typ. = 4.0 V) before falling below Vreset1 (typ. = 2.3 V)
				[Clearing condition]
				Writing 0 to this bit after reading it as 1
Note:	* Initialized	d by LVDI	٦.	

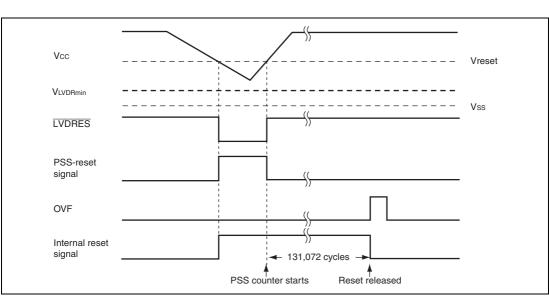
15.3.2 Low-Voltage Detection Circuit

(1) LVDR (Reset by Low Voltage Detect) Circuit

Figure 15.3 shows the timing of the LVDR function. The LVDR enters the module-standby state after a power-on reset is canceled. To operate the LVDR, set the LVDE bit in LVDCR to 1, wait for 50 μ s (t_{LVDON}) until the reference voltage and the low-voltage-detection power supply have stabilized by a software timer, etc., then set the LVDRE bit in LVDCR to 1. After that, the output settings of ports must be made. To cancel the low-voltage detection circuit, first the LVDRE bit should be cleared to 0 and then the LVDE bit should be cleared to 0. The LVDE and LVDRE bits must not be cleared to 0 simultaneously because incorrect operation may occur.

When the power-supply voltage falls below the Vreset voltage (typ. = 2.3 V or 3.6 V), the LVDR clears the \overline{LVDRES} signal to 0, and resets the prescaler S. The low-voltage detection reset state remains in place until a power-on reset is generated. When the power-supply voltage rises above the Vreset voltage again, the prescaler S starts counting. It counts 131,072 clock (ϕ) cycles, and then releases the internal reset signal. In this case, the LVDE, LVDSEL, and LVDRE bits in LVDCR are not initialized.

Note that if the power supply voltage (Vcc) falls below $V_{LVDRmin} = 1.0$ V and then rises from that point, the low-voltage detection reset may not occur.



If the power supply voltage (Vcc) falls below Vpor = 100 mV, a power-on reset occurs.

Figure 15.3 Operational Timing of LVDR Circuit



Table 18.2 DC Characteristics (2)

 V_{cc} = 3.0 V to 5.5 V, V_{ss} = 0.0 V, T_{a} = –20°C to +75°C, unless otherwise indicated.

		Applicable		Value			
Item Symbol		Pins Test Condition		Min	Тур	Max	Unit
Allowable output low current (per pin)	I _{ol}	Output pins except port 8	V _{cc} = 4.0 V to 5.5 V	—	—	2.0	mA
		Port 8	—		_	20.0	mA
		Port 8		—	_	10.0	mA
		Output pins except port 8	_	_	—	0.5	mA
Allowable output low current (total)	$\Sigma I_{\rm OL}$	Output pins except port 8	V _{cc} = 4.0 V to 5.5 V	_	_	40.0	mA
		Port 8	—		—	80.0	mA
		Output pins except port 8		_	—	20.0	mA
		Port 8	—		—	40.0	mA
Allowable output high current (per pin)	I –I _{OH} I	All output pins	V _{cc} = 4.0 V to 5.5 V	_	—	2.0	mA
					—	0.2	mA
Allowable output high current (total)	I –∑I _{OH} I	All output pins	V _{cc} = 4.0 V to 5.5 V	_	_	30.0	mA
				_	_	8.0	mA



A.3 Number of Execution States

The status of execution for each instruction of the H8/300H CPU and the method of calculating the number of states required for instruction execution are shown below. Table A.4 shows the number of cycles of each type occurring in each instruction, such as instruction fetch and data read/write. Table A.3 shows the number of states required for each cycle. The total number of states required for execution of an instruction can be calculated by the following expression:

Execution states = $I \times S_1 + J \times S_2 + K \times S_K + L \times S_L + M \times S_M + N \times S_N$

Examples: When instruction is fetched from on-chip ROM, and an on-chip RAM is accessed.

BSET #0, @FF00

From table A.4: $I=L=2, \quad J=K=M=N{=}0$

From table A.3: $S_1 = 2$, $S_1 = 2$

Number of states required for execution $= 2 \times 2 + 2 \times 2 = 8$

When instruction is fetched from on-chip ROM, branch address is read from on-chip ROM, and on-chip RAM is used for stack area.

JSR @@ 30

From table A.4: $I=2, \quad J=K=1, \quad L=M=N=0$

From table A.3:

$$\mathbf{S}_{\mathrm{I}} = \mathbf{S}_{\mathrm{J}} = \mathbf{S}_{\mathrm{K}} = 2$$

Number of states required for execution = $2 \times 2 + 1 \times 2 + 1 \times 2 = 8$



Appendix D Package Dimensions

The package dimensions that are shows in the Renesas Semiconductor Packages Data Book have priority.



